SPICE Device Model Si4825DDY



Vishay Siliconix

P-Channel 30 V (D-S) MOSFET

DESCRIPTION

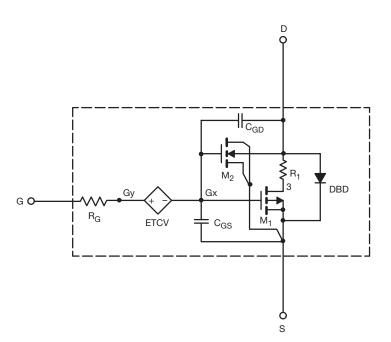
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},\ I_D=-\ 250\ \mu A$	1.7		V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -10 \text{ A}$	0.010	0.010	Ω
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -8 \text{ A}$	0.017	0.017	
Forward Transconductance ^a	g fs	$V_{DS} = -10 \text{ V}, I_D = -10 \text{ A}$	28	28	S
Diode Forward Voltage ^a	V _{SD}	I _S = - 3 A	- 0.75	- 0.75	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz	2580	2550	pF
Output Capacitance	C _{oss}		454	455	
Reverse Transfer Capacitance	C _{rss}		276	390	
Total Gate Charge	Qg	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -10 \text{ A}$	46	57	nC
			24	29.5	
Gate-Source Charge	Q _{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -10 \text{ A}$	8	8	
Gate-Drain Charge	Q _{gd}] [22	22	

Notes

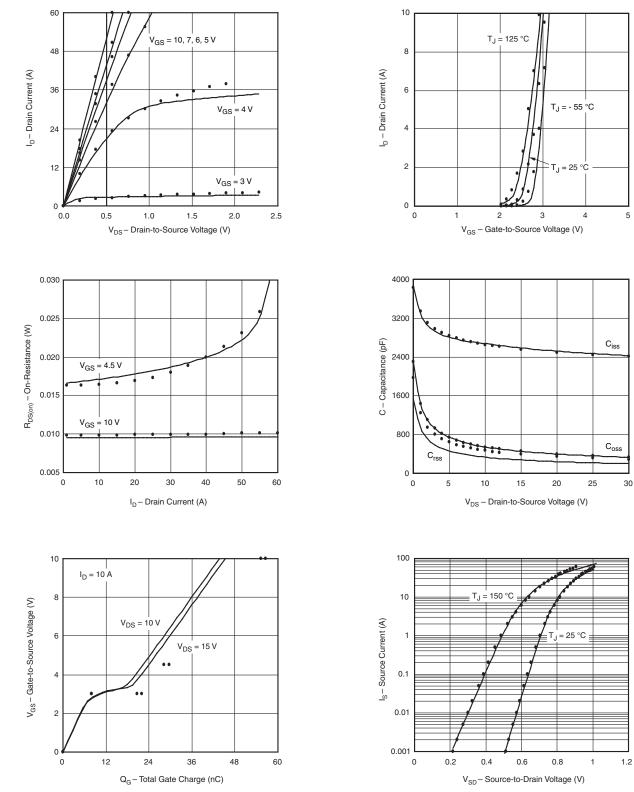
a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data.

S12-2770-Rev. B, 19-Nov-12

3

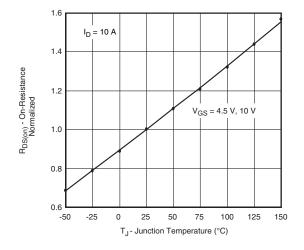
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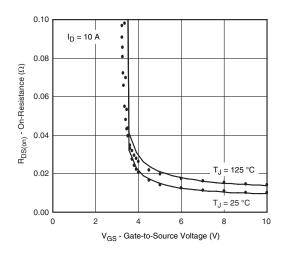
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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)





Note

• Dots and squares represent measured data.

S12-2770-Rev. B, 19-Nov-12

4



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